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December 2002

Revised August 2005

FSA3357 Low Voltage SP3T Analog Switch (3:1 Multiplexer/Demultiplexer)

General Description

The FSA3357 is a high performance, single-pole/triple-throw (SP3T) Analog Switch or 3:1 Multiplexer/Demultiplexer. The device is fabricated with advanced sub-micron CMOS technology to achieve high speed enable and disable times and low On Resistance. The break before make select circuitry prevents disruption of signals on the B₀, B₁, or B₂ Ports due to the switches temporarily being enabled during select pin switching. The device is specified to operate over the 1.65 to 5.5V V_{CC} operating range. The control input tolerates voltages up to 5.5V independent of the V_{CC} operating range.

Features

- Useful in both analog and digital applications
- Space saving US8 8-lead surface mount package
- Low On Resistance; < 9 Ω on typ @ 3.3V V_{CC}
- Broad V_{CC} operating range; 1.65V to 5.5V
- Rail-to-Rail signal handling
- Power down high impedance control input
- Overvoltage tolerance of control input to 7.0V
- Break before make enable circuitry
- 250 MHz 3dB bandwidth
- Space saving Pb-Free MicroPak[™] packaging

Applications

- Cell Phone
- PDA
- Video

Ordering Code:

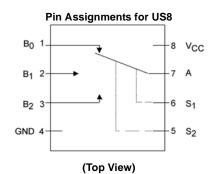
Product Order Number	Package Number	Code	Package Description	Supplied As
FSA3357K8X		Top Mark A357	8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide	3k Units on Tape and Reel
FSA3357L8X	MAC08A	FE	Pb-Free 8-Lead MicroPak, 1.6 mm Wide	5k Units on Tape and Reel

Pb-Free package per JEDEC J-STD-020B.

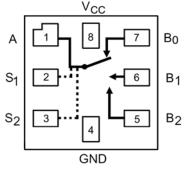
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Analog Symbols

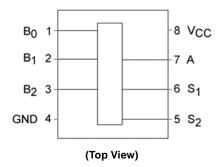


Pin Assignments for MicroPak



(Top Through View)

Connection Diagram



Pin Descriptions

Pin Names	Description
A ₁ , B ₀ , B ₁ , B ₂	Data Ports
S ₁ , S ₂	Control Input
	•

Function Table

S ₁	S ₂	Function
0	0	No Connection
1	0	B ₀ Connected to A
0	1	B ₁ Connected to A
1	1	B ₂ Connected to A

Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V
DC Switch Voltage (V_S) (Note 2)	-0.5V to V _{CC}
	+0.5V
DC Input Voltage (VIN) (Note 2)	-0.5V to +7.0V
DC Input Diode Current (I _{IK})	
@ $(I_{IK}) V_{IN} < 0V$	–50 mA
DC Output Current (I _{OUT})	128 mA
DC V _{CC} or Ground Current (I_{CC}/I_{GND})	±100 mA
Storage Temperature Range (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
Junction Temperature under Bias (T_J)	150°C
Junction Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C
Power Dissipation (P _D) @ +85°C	180 mW

Recommended Operating Conditions

(Note 3)

1.65V to 5.5V
0V to V_{CC}
0V to V_{CC}
0V to V_{CC}
$-40^{\circ}C$ to $+85^{\circ}C$
0 ns/V to 10 ns/V
0 ns/V to 5 ns/V
250°C/W
224°C/W

Note 1: Absolute maximum ratings are DC values beyond which the device may be damaged or have its useful life impaired. The datasheet specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside datasheet specifications.

Note 2: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 3: Control inputs must be held HIGH or LOW, they must not float.

DC Electrical	Characteristics
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Symbol	Devementer	Vcc		$T_A = +25^{\circ}C$		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Units	Conditions
V _{IH}	HIGH Level	1.65 – 1.95	0.75 V _{CC}			0.75 V _{CC}			
	Input Voltage	2.3 - 5.5	0.7 V _{CC}			0.7 V _{CC}		V	
V _{IL}	LOW Level	1.65 – 1.95			0.25 V _{CC}		0.25 V _{CC}	V	
	Input Voltage	2.3 – 5.5			0.3 V _{CC}		0.3 V _{CC}	v	
I _{IN}	Input Leakage Current	0 - 5.5			±0.1		±1.0	μA	$0 \leq V_{IN} \leq 5.5 V$
I _{OFF}	OFF State Leakage Current	1.65 - 5.5			±0.1		±1.0	μA	$0 \leq A, \ B_n \leq V_{CC}$
R _{ON}	Switch On Resistance	4.5		5.0	7.0		7.0		$V_{IN} = 0V, I_{O} = 30 \text{ mA}$
	(Note 4)			6.0	12.0		12.0		$V_{IN} = 2.4 V, I_{O} = -30 \text{ mA}$
				7.0	15.0		15.0		$V_{IN} = 4.5 V, I_O = -30 \text{ mA}$
		3.0		6.5	9.0		9.0		$V_{IN} = 0V, I_{O} = 24 \text{ mA}$
				9.0	20.0		20.0	Ω	$V_{IN} = 3V, I_{O} = -24 \text{ mA}$
		2.3		8.0	12.0		12.0		$V_{IN} = 0V, I_{O} = 8 \text{ mA}$
				11.0	30.0		30.0		$V_{IN} = 2.3V$, $I_O = -8$ mA
		1.65		10.0	20.0		20.0		$V_{IN} = 0V, I_{O} = 4 \text{ mA}$
				17.0	50.0		50.0		$V_{IN} = 1.65V, I_{O} = -4 \text{ mA}$
I _{CC}	Quiescent Supply Current	5.5			1.0		10.0	μA	$V_{IN} = V_{CC}$ or GND
	All Channels ON or OFF	5.5			1.0		10.0	μΑ	I _{OUT} = 0
ASR	Analog Signal Range	V _{CC}	0.0		V _{CC}	0.0	V _{CC}	V	
ΔR_{ON}	On Resistance Match	4.5		0.15					I _A = -30 mA, V _{Bn} = 3.15
	Between Channels	3.0		0.22				Ω	I _A = -24 mA, V _{Bn} = 2.1
	(Note 4)(Note 5)(Note 6)	2.3		0.31				12	I _A = -8 mA, V _{Bn} = 1.6
		1.65		0.62					$I_A = -4 \text{ mA}, V_{Bn} = 1.15$
R _{flat}	On Resistance Flatness	5.0		6.0					$I_A = -30 \text{ mA}, \ 0 \leq V_{Bn} \leq V_{CC}$
	(Note 4)(Note 5)(Note 7)	3.3		12.0				Ω	$I_A = -24 \text{ mA}, \ 0 \leq V_{Bn} \leq V_{CC}$
		2.5		40.0				22	$I_A = -8 \ mA, \ 0 \leq V_{Bn} \leq V_{CC}$
		1.8		140.0					$I_A = -4 \text{ mA}, 0 \le V_{Bn} \le V_{CC}$

DC Electrical Characteristics (Continued)

Note 4: Measured by the voltage drop between A and B_n pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B_n Ports).

Note 5: Parameter is characterized but not tested in production.

Note 6: $\Delta R_{ON} = R_{ON} \text{ max} - R_{ON} \text{ min measured at identical V}_{CC}$, temperature and voltage levels.

Note 7: Flatness is defined as the difference between the maximum and minimum value of On Resistance over the specified range of conditions.

AC Electrical Characteristics

0	Description	V _{cc}		$T_A = +25^{\circ}C$		T _A = -40°	C to +85°C	l la la	Conditions	Figure
Symbol	Parameter	(V)	Min	Тур	Max	Min	Max	Units	Conditions	Number
t _{PHL}	Propagation Delay	1.65 - 1.95		2.0						
t _{PLH}	Bus to Bus	2.3 - 2.7		1.1						Figures
	(Note 8)	3.0 - 3.6		0.7				ns	V _I = OPEN	1, 2
		4.5 - 5.5		0.4						
t _{PZL}	Output Enable Time	1.65 - 1.95	5.0		32.0	5.0	34.0			
t _{PZH}	Turn on Time	2.3 - 2.7	3.0		15.0	3.0	16.5		$V_I = 2 \times V_{CC}$ for t_{PZL}	Figures
	(A to B _n)	3.0 - 3.6	2.0		9.5	2.0	11.0	ns	$V_I = 0V$ for t_{PZH}	1, 2
		4.5 - 5.5	1.5		6.5	1.5	7.0			
t _{PLZ}	Output Disable Time	1.65 - 1.95	3.0		14.0	3.0	14.5			Figures 1, 2
t _{PHZ}	Turn Off Time	2.3 - 2.7	2.0		7.2	2.0	7.8		$V_I = 2 \times V_{CC}$ for t_{PLZ}	
	(A Port to B _n Port)	3.0 - 3.6	1.5		5.1	1.5	5.5	ns	$V_I = 0V$ for t_{PHZ}	
		4.5 - 5.5	0.8		3.7	0.8	4.0			
t _{B-M}	Break Before Make Time	1.65 - 1.95	0.5			0.5				Figure 3
	(Note 9)	2.3 - 2.7	0.5			0.5				
		3.0 - 3.6	0.5			0.5		ns		
		4.5 - 5.5	0.5			0.5				
Q	Charge Injection (Note 9)	5.0		3.0					C _L = 0.1 nF, V _{GEN} = 0V	
		3.3		2.0				pC	$R_{GEN} = 0\Omega$	Figure 4
OIRR	Off Isolation (Note 10)	1.65 - 5.5		-58.0				9	$R_L = 50\Omega$	Figure 5
								dB	f = 10MHz	Figure 5
Xtalk	Crosstalk	1.65 - 5.5		-60.0				-iD	$R_L = 50\Omega$	Figure 0
								dB f = 10MHz		Figure 6
BW	-3dB Bandwidth	1.65 - 5.5		250.0				MHz	$R_L = 50\Omega$	Figure 9
THD	Total Harmonic Distortion	İ							R _L = 600Ω	1
	(Note 9)	5.0		.01				%	0.5 V _{P-P}	
									f = 600 Hz to 20 KHz	

Note 8: This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On Resistance of the switch and the 50 pF load capacitance, when driven by an ideal voltage source (zero output impedance).

Note 9: Guaranteed by Design.

Note 10: Off Isolation = 20 $\log_{10} [V_A / V_{Bn}]$

Capacitance (Note 11)

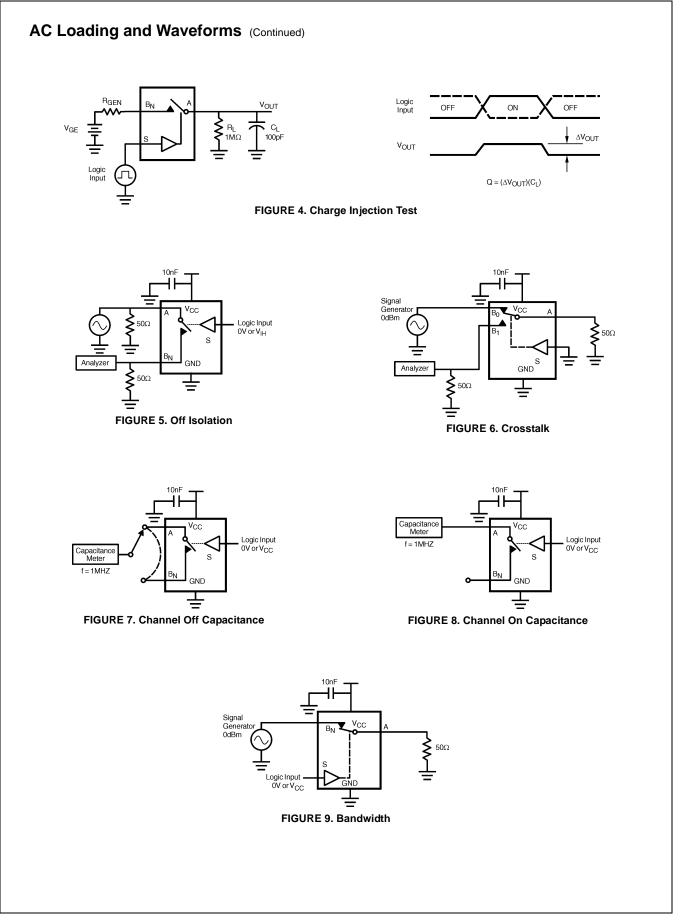
Symbol	Parameter	Тур	Max	Units	Conditions	Figure Number
C _{IN}	Control Pin Input Capacitance	2.0		pF	$V_{CC} = 0V$	
C _{IO-B}	B Port Off Capacitance	3.6		pF	$V_{CC} = 5.0V$	Figure 7
C _{IOA-ON}	A Port Capacitance When Switch Is Enabled	14.5		pF	$V_{CC} = 5.0V$	Figure 8

Note 11: $T_A = +25$ °C, f = 1 MHz, Capacitance is characterized but not tested in production.

FSA3357

AC Loading and Waveforms **\$** 500Ω FROM • OUTPUT **ξ**^{500Ω} UNDER 50pl TEST Note: Input driven by 50Ω source terminated in 50Ω Note: \mathbf{C}_{L} includes load and stray capacitance Note: Input PRR = 1.0 MHz; t_W = 500 ns FIGURE 1. AC Test Circuit t_f = 2.5 ns - t, = 2.5 ns $v_{\rm CC}$ 90% t_r= 2.5 ns→ • t_f = 2.5 ns 90 CONTROL INPUT V_{CC} 50% 50% 90% 909 SWITCH INPUT 10% 10% 50% GND 50% t_{PZL} 10% 10% V_{TRI} GND t_{PLH} t_{PHL} OUTPUT 50% V_{OL}+0.3V V_{он} VOL OUTPUT 50% 50% t_{PZH} -- t_{PHZ} √он V_{OL} V_{OH}-0.3V OUTPUT 50% V_{tri} FIGURE 2. AC Waveforms VIN Vout Logic Input 35 pF \$500Ω VOUT Logic Input 0.9 x V_{OUT} tD FIGURE 3. Break Before Make Interval Timing



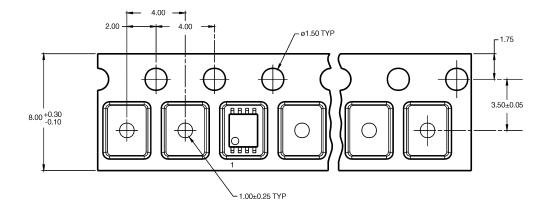


Tape and Reel Specification

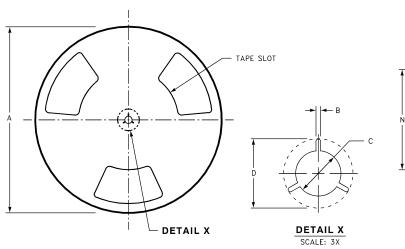


Package	Таре	Number	Cavity	Cover Tape
Designator	Section	Cavities	Status	Status
	Leader (Start End)	125 (typ)	Empty	Sealed
K8X	Carrier	250	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed





REEL DIMENSIONS inches (millimeters)

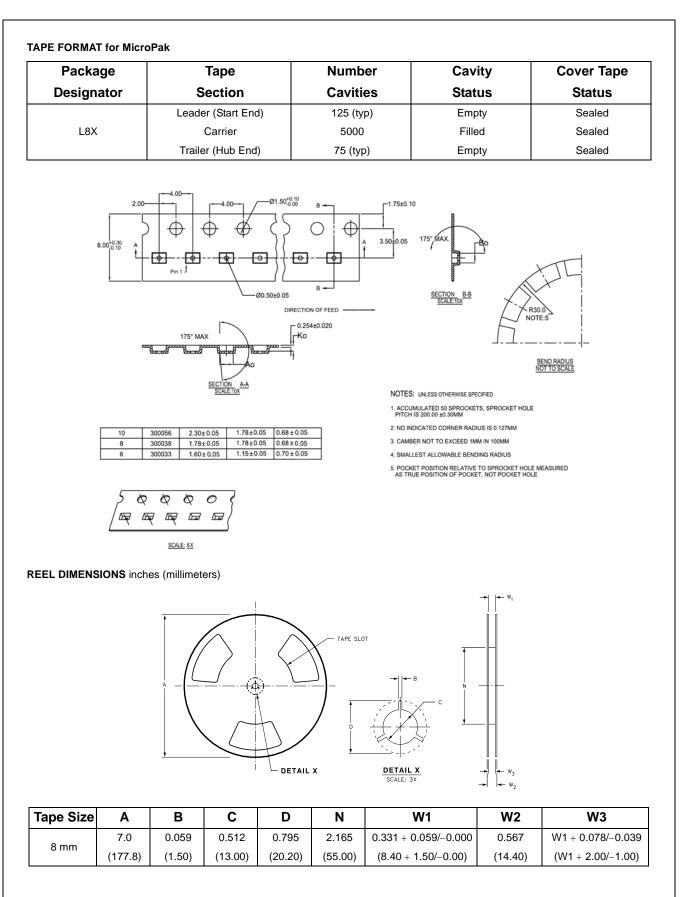


→ →	₩ ₃ ₩ ₂

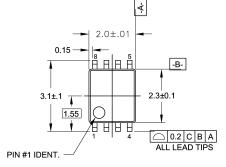
W₁

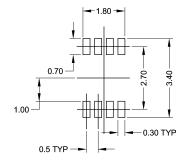
Tape Size	Α	В	С	D	Ν	W1	W2	W3
8 mm	7.0	0.059	0.512	0.795	2.165	0.331 + 0.059/- 0.000	0.567	W1 + 0.078/-0.039
	(177.8)	(1.50)	(13.00)	(20.20)	(55.00)	(8.40 + 1.50/-0.00)	(14.40)	(W1 + 2.00/-1.00)

FSA3357

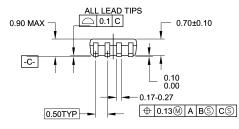


Physical Dimensions inches (millimeters) unless otherwise noted





LAND PATTERN RECOMMENDATION

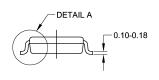


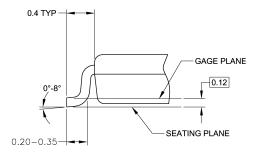
A. CONFORMS TO JEDEC REGISTRATION MO-187 B. DIMENSIONS ARE IN MILLIMETERS.

AND TIE BAR EXTRUSIONS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH,

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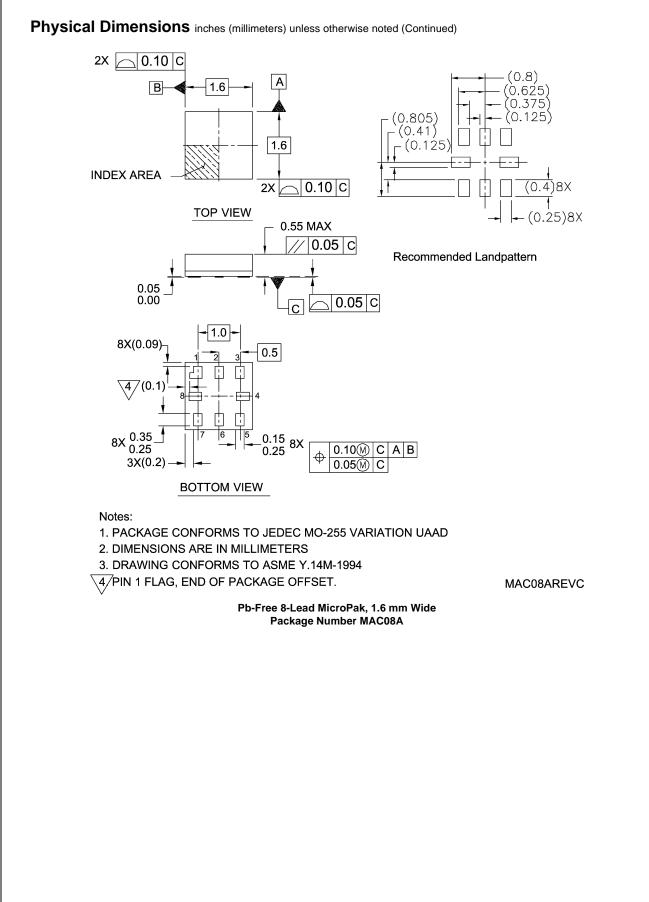


MAB08AREVC

NOTES:

8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide Package Number MAB08A

FSA3357



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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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